



## SEMIPONT® 2

## Power Bridge Rectifiers

## SKD 60

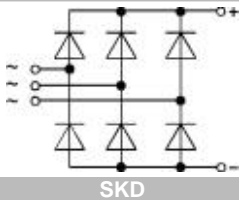
## Features

- Robust plastic case with screw terminals
- Large, isolated base plate
- Blocking voltage to 1600 V
- High surge currents
- Three phase bridge rectifier
- Easy chassis mounting
- UL recognized, file no. E 63 532

## Typical Applications

- Three phase rectifiers for power supplies
- Input rectifiers for variable frequency drives
- Rectifiers for DC motor field supplies
- Battery charger rectifiers

<sup>1)</sup> Painted metal sheet of minimum  
250 x 250 x 1 mm:  $R_{th(c-a)} = 1,8 \text{ K/W}$



$V_{RSM}$	$V_{RRM}, V_{DRM}$	$I_D = 60 \text{ A (full conduction)}$
V	V	$(T_c = 102 \text{ °C})$
400	400	SKD 60/04
800	800	SKD 60/08
1200	1200	SKD 60/12
1400	1400	SKD 60/14
1600	1600	SKD 60/16

Symbol	Conditions	Values	Units
$I_D$	$T_c = 85 \text{ °C}$	92	A
	inductive load		A
	$T_a = 45 \text{ °C, chassis } ^1)$	21	A
	$T_a = 45 \text{ °C; P13A/125 (R4A/120)}$	27 (30)	A
$I_{FSM}$	$T_{vj} = 25 \text{ °C; 10 ms}$	1000	A
	$T_{vj} = 125 \text{ °C; 10 ms}$	850	A
$i^2t$	$T_{vj} = 25 \text{ °C; 8,3 ... 10 ms}$	5000	A <sup>2</sup> s
	$T_{vj} = 125 \text{ °C; 8,3 ... 10 ms}$	3600	A <sup>2</sup> s
$V_F$	$T_{vj} = 25 \text{ °C; } I_F = 150 \text{ A}$	max. 1,6	V
$V_{(TO)}$	$T_{vj} = 125 \text{ °C}$	max. 0,85	V
$r_T$	$T_{vj} = 125 \text{ °C}$	max. 5	m
$I_{RD}$	$T_{vj} = 25 \text{ °C; } V_{DD} = V_{DRM}; V_{RD} = V_{RRM}$	max. 0,5	mA
	$T_{vj} = 125 \text{ °C; } V_{RD} = V_{RRM}$	2	mA
$R_{th(j-c)}$	per diode	1	K/W
	total	0,167	K/W
$R_{th(c-s)}$	total	0,05	K/W
$T_{vj}$		- 40 ... + 125	°C
$T_{stg}$		- 40 ... + 125	°C
$V_{isol}$	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 ( 3000 )	V
$M_s$	to heatsink	$5 \pm 15 \%$	Nm
$M_t$	to terminals	$5 \pm 15 \%$	Nm
m		165	g
Case		G 18	

## Diagrams

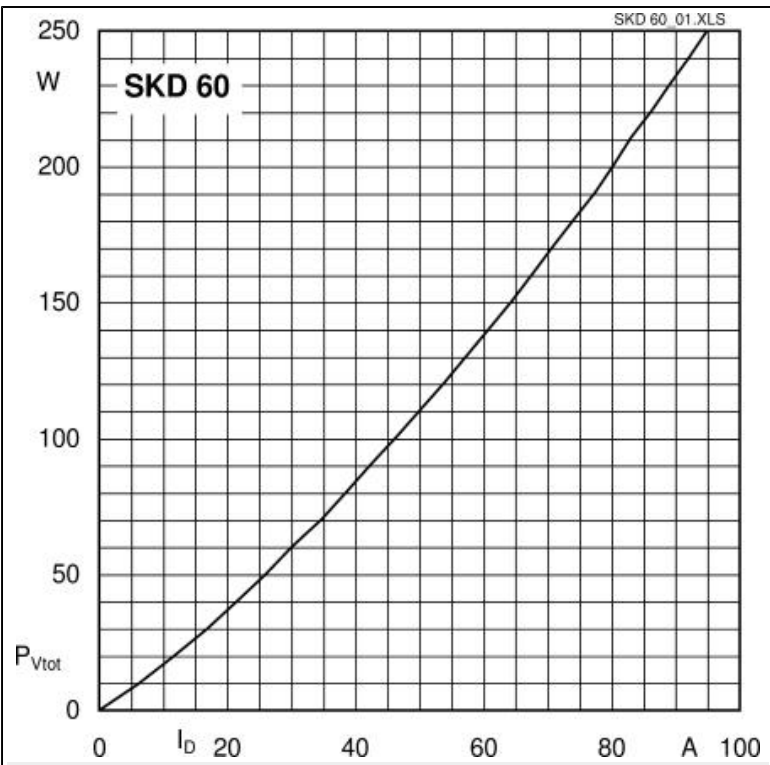


Fig. 3L Power dissipation vs. output current

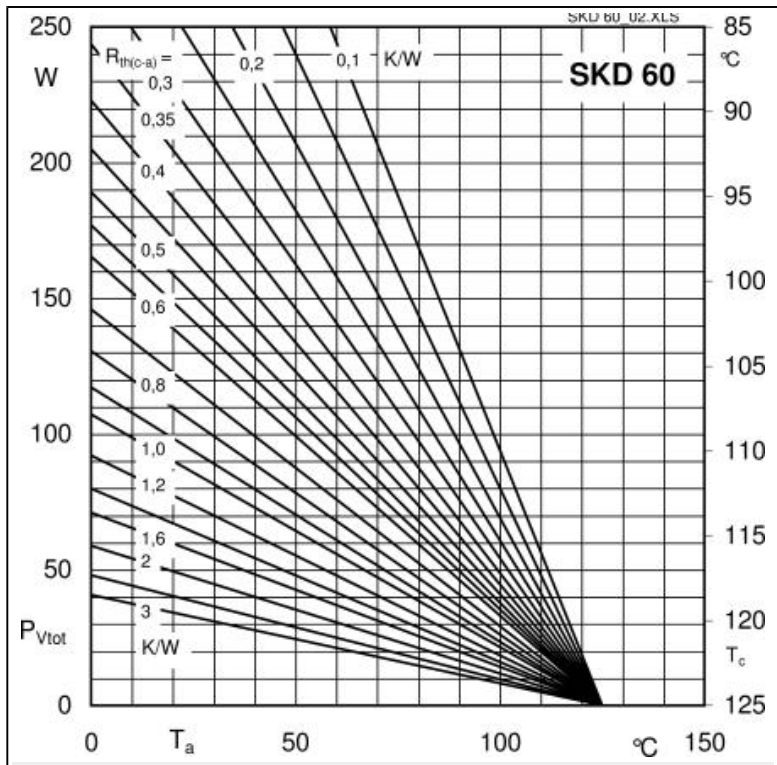


Fig. 3R Power dissipation vs. case temperature

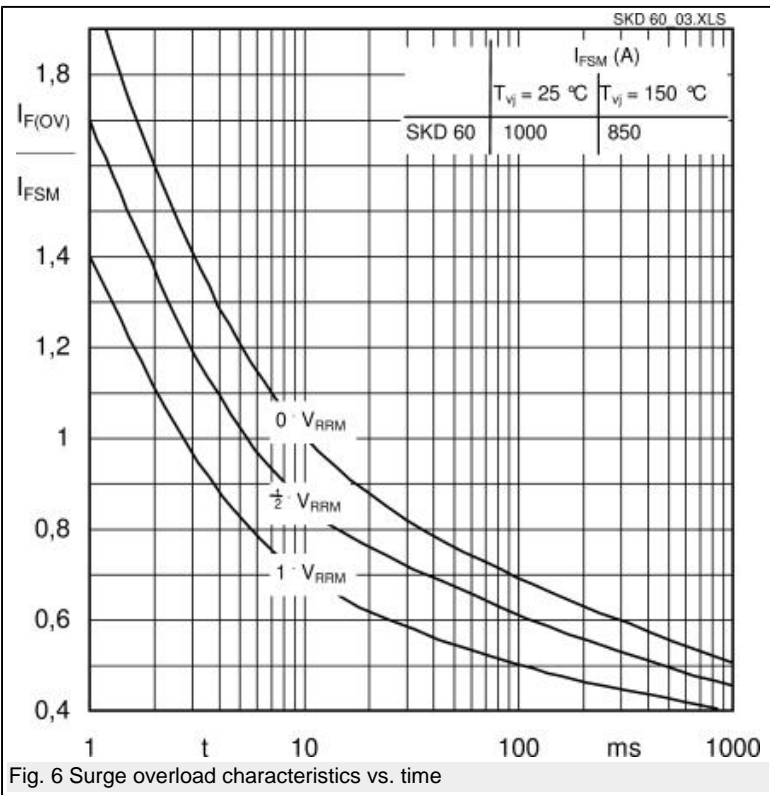


Fig. 6 Surge overload characteristics vs. time

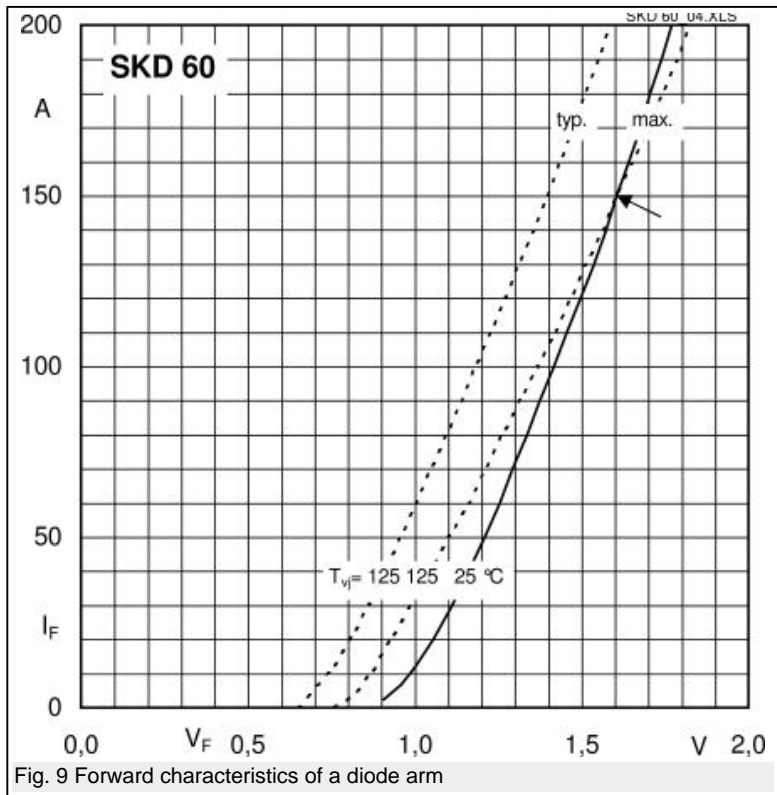


Fig. 9 Forward characteristics of a diode arm

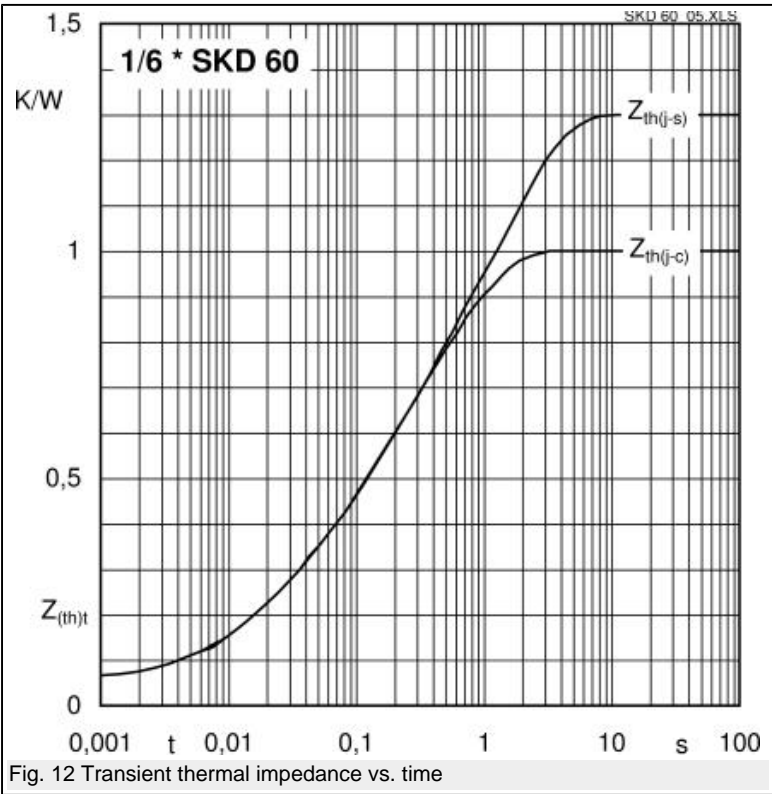
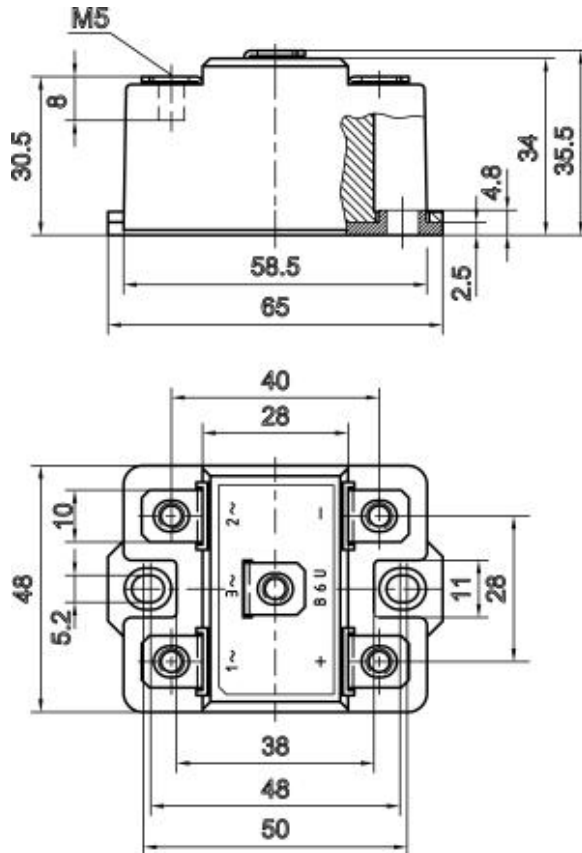


Fig. 12 Transient thermal impedance vs. time

## Cases / Circuits

Dimensions in mm



Case G 18

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.

